#### **High Frequency Stratum 3 MEMS VCTCXO Advanced Information**



#### ■ Features, Benefits and Applications

- Any frequency between 60.000001 and 220 MHz
- ±4.6 PPM total frequency stability over 20 years
- <±0.37 PPM (370 PPB) 24-hour hold-over stability
- ±0.1 PPM (100 PPB) over-temperature stability (0 70°C).
- Excellent phase jitter: 0.5 ps (12 kHz to 20 MHz)
- Voltage control with±12.5 PPM pull range
- LVCMOS/HCMOS compatible output
- Three 4-pin packages: 3.2 x 2.5, 5.0 x 3.2, 7.0 x 5.0 (mmxmm)
- Contact SiTime for the following options:
- SoftEdge<sup>TM</sup> Configurable rise/fall time control
- · Extended commercial and industrial temperature range options
- · Fixed frequency TCXO option
- 2.5 x 2.0 footprint compatbile package support
- Outstanding silicon reliability of 2 FIT (10x improvement over quartz-based devices)
- Ideal for telecom, networking, smart meter, and IP timing applications

#### ■ Specifications

#### **Electrical Characteristics**

Parameter	Symbol	Min.	Тур.	Max.	Unit	Condition	
Output Frequency Range	f	60.000001	_	220	MHz		
Frequency Stability				l .			
Overall stability	F_stab	-4.6	-	+4.6	PPM	Inclusive of temperature, 20 year aging, supply voltage are output load	
Stability over temperature	F_temp	-0.10	-	+0.10	PPM	0 to 70 °C (Ordering code: Q)	
		-0.20	-	+0.20	PPM	-20 to 70 °C (Ordering code: P)	
Supply Voltage	F_vdd	-0.025	-	+0.025	PPM	±5% Vdd	
Output Load	F_load	-0.005	-	+0.005	PPM	±10% of 15 pF load	
24 hour hold-over stabilty	F_hold	-0.37	-	+0.37	PPM	Inclusive of temperature, 24 hour aging, supply voltage and output load	
Initial Tolerance	F_init	-1	_	1	PPM	at 25°C	
Operating Temperature Range	T_use	0	-	+70	°C	Commercial. Contacct SiTime for extended commercial (-20 to 70 °C) or industrial temperature (-20 to 45 °C) range support	
Supply Voltage	Vdd	2.25	2.5	2.75	V	Any supply voltage between 2.5V and 3.3V is supported to 1 decimal	
		2.97	3.3	3.63	V	of accuracy	
Pull Range	PR	±12.5		PPM			
Control Voltage	VC	10	_	90	%VDD		
Linearity	Lin	_	_	1	%		
Frequency Change Polarity	-	Р	Positive slope		_		
Control Voltage -3dB Bandwidth	V_BW	-	-	8	kHz		
Current Consumption	ldd	-	33	35	mA	No load condition, f = 100MHz, Vdd = 2.5 V or 3.3 V	
Duty Cycle	DC	45	-	55	%	All Vdds.	
Rise/Fall Time	Tr, Tf	_	1.5	2	ns	15 pF load, 10% - 90% Vdd	
Output Voltage High	VOH	90%	-	-	Vdd	IOH = 7mA, Vdd = 3.3V IOH = 4.5mA, Vdd = 2.5V	
Output Voltage Low	VOL	-	-	10%	Vdd	IOL = 7mA, Vdd = 3.3V IOL = 4.5mA, Vdd = 2.5V	
Output Load	Load	-	-	15	pF	At maximum frequency and supply voltage. Contact SiTime for higher output load options	
Startup Time	T_start	-	-	10	ms	Measured from the time Vdd reaches its rated minimum value	
RMS Period Jitter	T_jitt	-	1.7	2.5	ps	f = 100 MHz, Integration bandwidth = 12 kHz to 20MHz,	
RMS Phase Jitter (random)	T_phj	-	0.5	-	ps	f = 100 MHz, Integration bandwidth = 12 kHz to 20MHz, all Vdds	

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# High Frequency Stratum 3 MEMS VCTCXO Advanced Information



■ Specifications (Cont.)

#### **Pin Description Tables**

Pin #1 Functionality			
VIN			
0 - Vdd: produces voltage dependent frequency change			

Pin Map				
Pin	Connection			
1	VC			
2	GND			
3	CLK			
4	VDD			

#### **Absolute Maximum Ratings**

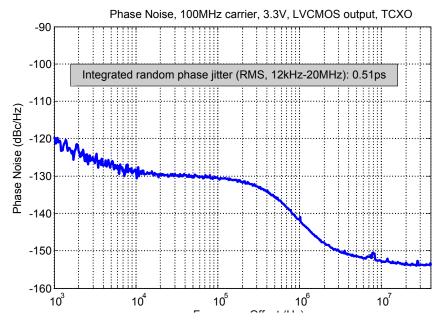
Attempted operation outside the absolute maximum ratings of the part may cause permanent damage to the part. Actual performance of the IC is only guaranteed within the operational specifications, not at absolute maximum ratings.

Parameter	Min.	Max.	Unit
Storage Temperature	-65	150	°C
VDD	-0.5	4	V
Electrostatic Discharge (Human Body Model)	_	2000	V
Soldering Temperature (follow standard Pb free soldering guidelines)	-	260	°C
Number of Program Writes	-	1	NA
Program Retention over -40 to 125°C, Process, VDD (0 to 3.65 V)	1,000+	-	years

#### **Environmental Compliance**

Parameter	Condition/Test Method
Mechanical Shock	MIL-STD-883F, Method 2002
Mechanical Vibration	MIL-STD-883F, Method 2007
Temperature Cycle	JESD22, Method A104
Solderability	MIL-STD-883F, Method 2003
Moisture Sensitivity Level (MSL)	MSL1 @ 260°C

#### Phase Noise Plot[1]



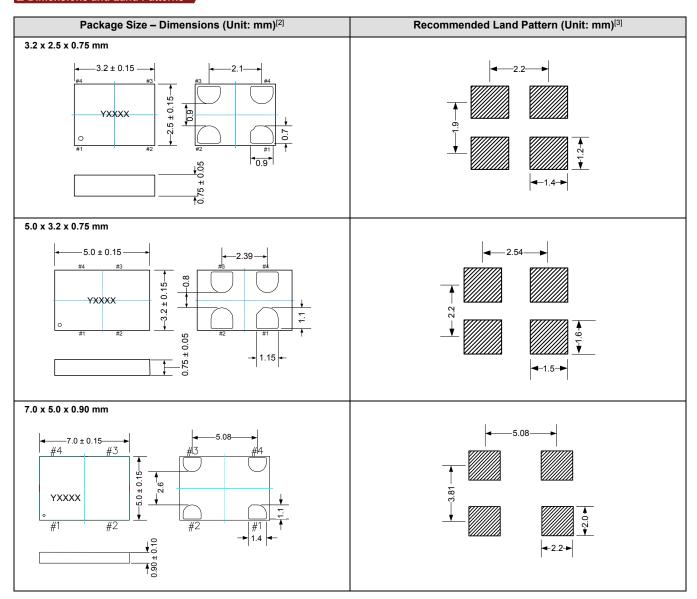
#### Note:

The maximum offset frequency is half of the clock (or carrier) frequency for a digital clock.

### High Frequency Stratum 3 MEMS VCTCXO **Advanced Information**



#### ■ Dimensions and Land Patterns

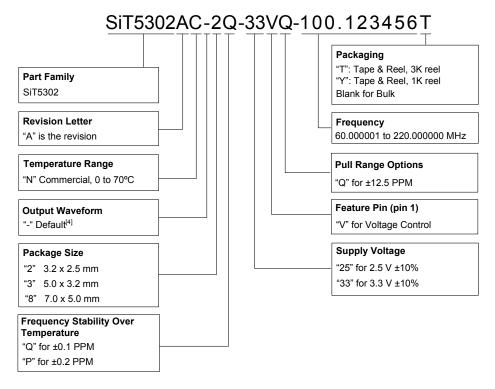


2. Top marking:Y denotes manufacturing origin and XXXX denotes manufacturing lot number. The value of "Y" will depend on the assembly location of the device 3. Refer to application note AN10002 for recommended RLL to power supply bypass for better supply noise immunity.

# High Frequency Stratum 3 MEMS VCTCXO Advanced Information



■ Part No. Guide - How to Order



#### Notes:

4. Contact SiTime for SoftEdge<sup>TM</sup> output waveform that reduces EMI and is similar to clipped sinewave in functionality.

#### Frequency Stability vs. Temperature Range Options[5]

FrequencyStability	Temperature	Supply Voltage	
Over-temperature (PPM)	Range (°C)	2.5 V	3.3 V
±0.1	0 to +70	✓	✓
	-20 to +70	Contact SiTime	
±0.2	0 to +70	✓	✓
	-20 to +70	Contact SiTime	

 ${\bf 5.} \ \ {\bf Contact} \ {\bf SiTime} \ {\bf for} \ {\bf wider} \ {\bf operating} \ {\bf temperature} \ {\bf range} \ {\bf support}.$ 

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